

## FEATURES:

- Detects ionizing radiation pulses
- 100% tested/certified detection threshold level
- Adjustable circumvention period
- 100% testable with built-in test
- Detection threshold adjustability
- Single +5V operation
- Radiation hardness guaranteed
- Compliant to MIL-PRF-38534 Class H
- Flat pack (F) or DIP (L) packages

## DESCRIPTION:

Space Electronics' HSN-1000 radiation-hardened Hybrid Nuclear Event Detector (NED) senses ionizing radiation pulses generated by a nuclear event, such as the detonation of a nuclear weapon, and rapidly switches its output from the normal high state to a low state with a propagation delay time of less than 20ns. The active low Nuclear Event Detection signal ( $\overline{\text{NED}}$ ) is used to initiate a wide variety of circumvention functions, thus preventing upset and burnout of electronic components. The  $\overline{\text{NED}}$  output is also used to initiate both hardware and software recovery. This high-speed, 14-pin hybrid detector is used in electronic systems as a general-purpose circumvention device to protect memory, stop data processing, and drive power supply switches as well as signal clamps.

The HSN-1000 is guaranteed to operate through three critical environments: ionizing dose rate [ $10^{12}$  rad(Si)/s], gamma total dose [ $10^6$  rad(Si)], and neutron fluence [ $5 \times 10^{13}$  n/cm<sup>2</sup>]. In addition, the device is designed to function throughout the transient neutron pulse. The hybrid's discrete design ensures a controlled response in these radiation environments as well as immunity to latchup. Each HSN-1000's detection level and functionality are tested in an ionizing dose rate environment. A certificate is provided with each serialized hybrid, reporting the radiation test results and guaranteeing its performance. The device is also lot qualified in the total dose and neutron environments to ensure performance.

The detection threshold of the HSN-1000 is adjustable within the range of  $2 \times 10^5$  rad(Si)/s to  $2 \times 10^7$  rad(Si)/s. This detection level can be preset by SEI or adjusted by the user. Less than a 30% variation in detection threshold can be expected over the entire operating temperature range.

**TABLE 1. PIN DESCRIPTION**

PIN NUMBER	PIN FUNCTION
1	Load Voltage, $V_L$
2	Nuclear Event Detector, NED
3	No Connection
4	External Capacitor
5	External Capacitor
6	Built In Test, BIT
7	Package Ground and Case
8	PIN Diode Bias, $V_B$
9	Threshold Adjust
10	No Connection
11	No Connection
12	No Connection
13	No Connection
14	Hardened Supply Voltage, $V_H$

**TABLE 2. ELECTRICAL CHARACTERISTICS**

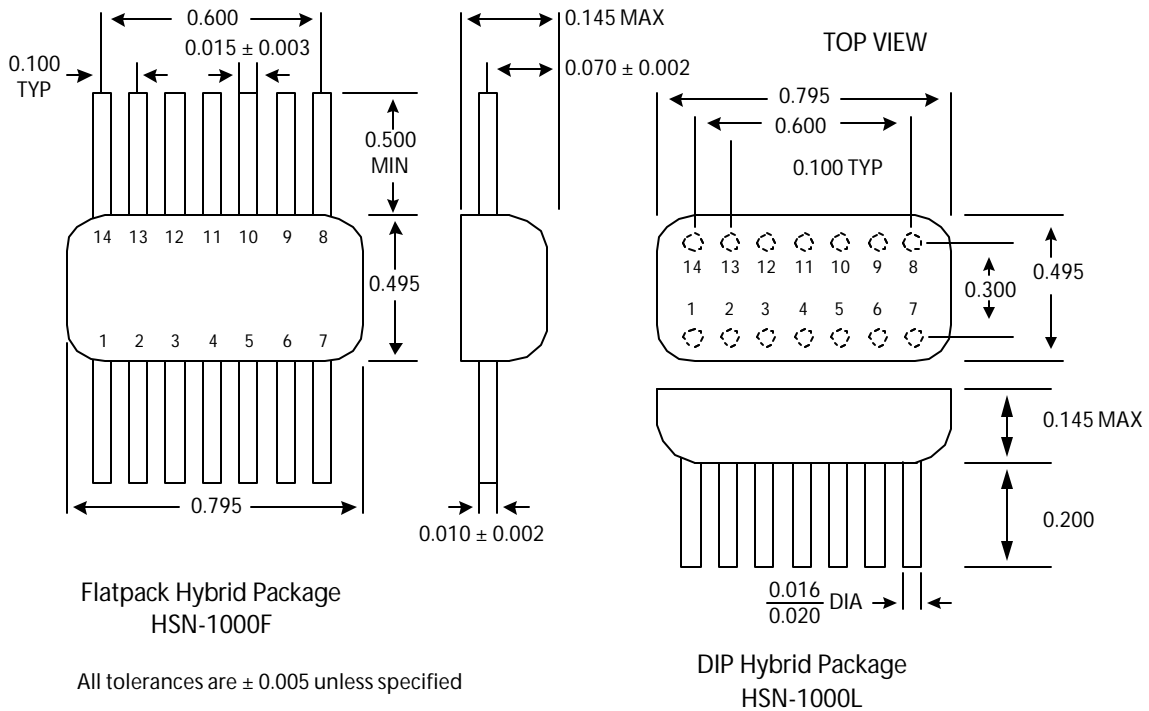
PARAMETER	SYMBOL	CONDITIONS $-55\text{ }^\circ\text{C} \leq T_A \leq 125\text{ }^\circ\text{C}$	MIN	MAX	UNIT	GROUP A SUBGROUP
Hardened Supply Voltage	$V_H$		4.5	5.5	V	1,2,3
Hardened Supply Current - Standby <sup>1</sup> - Operational <sup>2</sup>	$I_H$	$V_H = 5.5\text{V}$	-- --	30 120	mA	1,2,3
Load Voltage	$V_L$		--	20	V	1,2,3
Load Current - Standby <sup>1</sup> - Operational <sup>2</sup>	$I_L$	$V_L = 20\text{V}$	-- --	100 2.25	$\mu\text{A}$ mA	1,2,3
PIN Diode Bias Voltage - Standby <sup>1</sup>	$V_B$		4.5	20	V	1,2,3
PIN Diode Bias Current - Standby <sup>1</sup>	$I_B$		--	100	$\mu\text{A}$	1,2,3
Built-In-Test (BIT) <sup>3,4</sup>	$V_{IH}$ $I_{IH}$ $V_{IL}$ $I_{IL}$ $t_{PW}$	$V_{IH} = 4.0\text{V}$  $V_{IL} = 0.5\text{V}$ Pin 9 Open, $V_H = 4.0\text{V}$	4.0 -- -- -- 10	5.5 25 0.5 10 --	V mA V $\mu\text{A}$ $\mu\text{s}$	7,8 1,2,3 7,8 1,2,3 9,10,11
NED	$V_{OH}$ $V_{OL}$	$V_L = 20\text{V}$ , $I_{OH} = -100\text{ }\mu\text{A}$ $I_{OL} = 10\text{ mA}$ $I_{OL} = 100\text{ mA}$	18.5 -- --	-- 0.6 1.0	V	1,2,3 1,2,3
Radiation Propagation Delay Time <sup>5</sup>	$t_D$		--	20	ns	

1. Standby mode is the normal state of the device, defined as having the  $\overline{\text{NED}}$  output (pin 2) in the "high" state.
2. Operational mode is in effect during the timeout period of the NED signal, characterized by having the NED output in the "low" state, causing the greatest current draw of the device.
3. BIT electrical characteristics are not guaranteed over the radiation range.
4. BIT may not meet specification when only a resistor is used to adjust the detection level. To use BIT in this situation, it is advised that a series resistor/capacitor combination is used.
5. Guaranteed but not tested over temperature. Time delay,  $t_D$ , is measured at 50% points from the rising edge of the radiation pulse to the falling edge of the  $\overline{\text{NED}}$  output at approximately 10 times the detection level.

## Radiation Hardness Characteristics

Dose Rate (operate-through)	$1 \times 10^{12}$	rad(Si)/sec
Total Dose	$1 \times 10^6$	rad(Si)
Neutron Fluence	$5 \times 10^{13}$	n/cm <sup>2</sup>
Approximate Detection Range	$2 \times 10^5 - 2 \times 10^7$	rad(Si)/sec

## MECHANICAL DIMENSIONS



Note: All dimensions in inches.